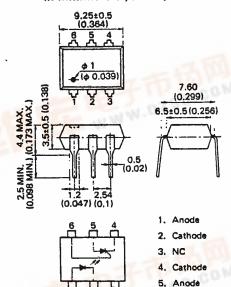
# PHOTO SCR COUPLERS PS3001(1), PS3002(1)

# PHOTO SCR COUPLER

### DESCRIPTION

The PS3001 and PS3002 are optically coupled isolators containing GaAs infrared emitting diode and a PNPN silicon photo SCR.

# PACKAGE DIMENSIONS in millimeters (inches)



(Top View)

6. Gate

# **FEATURES**

High Voltage Isolation
 Low Turn on Current
 12 mA MAX.

- Plastic dual-in-line package
- High Speed Switching
- Economical, Compact.

# **APPLICATIONS**

- Interface circuit for various instrumentations, control equipments
- · Replaceable from a reed relay

# ABSOLUTE MAXIMUM RATINGS (Ta=25 °C)

# Diode

Reverse Voltage	VR	6 V.
Forward Current (DC)	IF	80 mA
Peak Forward Current	IFP	3 A
Power Dissipation	PD	100 mW
SCR		
Peak Off and Reverse Voltage	VDRM, V	RRM PS3001 200 V
	•	PS3002 400 V
Direct On-State Current	IT	300 mA
Peak pulse current *1	<sup>Į</sup> TP	3 A
Peak surge on Current	ITSM	3 A
Power Dissipation	PSCR	350 mW
Isolation Voltage *2	BV	2500 - VAC
Storage Temperature	Tstg	-55 to +125 °C
Operation Temperature	Topt	-55 to +100 °C
Lead Soldering Time (at 260 °C)		10 s.



# PS3001(1), PS3002(1)

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# ELECTRICAL CHARACTERISTICS (Ta=25 °C)

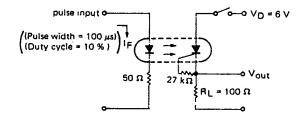
	CHARACTERISTIC	SYMBÓL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
	Forward Voltage	٧F		1.1	1.4	v	IF=20 mA
Diode	Reverse Current	IR			10	μА	VR=6 V
L	Junction Capacitance	Ct	T	50	1	ρF	V=0, f=1.0 MHz
	Peak Off-State Current	DRM	Ī	-	10	μА	VDRM=Rated
	Reverse Current	IRRM		<u> </u>	10	μА	RGK=27 kΩ Ta=100 °C
SCR	On State Voltage	VTM	1		1.3	v	IT=300 mA
Photo	Holding Current	ĮН		0.2	1	mA	R <sub>GK</sub> =27 kΩ, V <sub>D</sub> =24 V
	Rate of rise of forward blocking Voltage	dV/dt	0.5	1.0		V/μs	V <sub>DRM</sub> =Rated RGK=27 kΩ, Ta=100 °C
ļ	Turn on Current *3	IFT		5	12	mA	VD=6 V, RGK=27 kΩ
_	Isolation breakdown Voltage	V1-2	2500			VDC	DC/1 minute
Coupled	Isolation Resistance	R <sub>1.2</sub>	1011			Ω	Vin-out=1,0 kV
ی	Isolation Capacitance	C <sub>1.2</sub>		0.8		pF	V=0, f=1.0 MHz
	Turn on Time *4	<sup>t</sup> on		10		μs	I <sub>FT</sub> =50 mA, V <sub>D</sub> =6 V R <sub>GK</sub> =27 kΩ, R <sub>L</sub> =100 Ω

<sup>\*1</sup> pulse width = 100 μs Repetitive Frequency = 100 Hz

\*2 Measuring Condition
DC voltage for 1 minute at Ta = 25 °C; RH = 60 %
Between input (pin No. 1, 2 and No. 3 Common)
and output (pin No. 4, 5 and No. 6 Common)

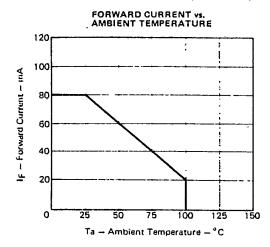
\*3 f<sub>FT</sub> rank KX : to 12 mA LX : to 7 mA

# \*4 Turn on Time Test Circuit

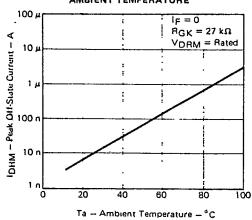


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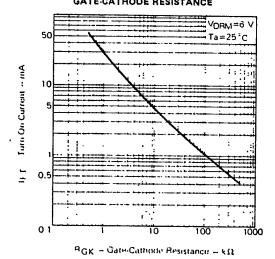
# TYPICAL CHARACTERISTICS (Ta=25 °C)



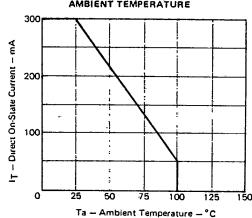
## PEAK OFF-STATE CURRENT VS. AMBIENT TEMPERATURE



# TURN ON CURRENT VS. GATE-CATHODE RESISTANCE



# DIRECT ON-STATE CURRENT vs. AMBIENT TEMPERATURE



### TURN ON CURRENT vs. AMBIENT TEMPERATURE

